TSC101

High side current sense amplifier

Features

- Independent supply and input common-mode voltages
- Wide common-mode operating range: 2.8 to 30 V
- Wide common-mode surviving range: -0.3 to 60 V (load-dump)
- Wide supply voltage range: 4 to 24 V
- Low current consumption: I_{CC} max = 300 µA
- Internally fixed gain: 20 V/V, 50 V/V or 100 V/V
- Buffered output

Applications

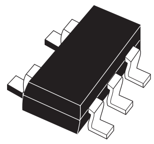
- Automotive current monitoring
- Notebook computers
- DC motor controls
- Photovoltaic systems
- Battery chargers
- Precision current sources

Description

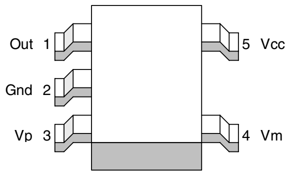
The TSC101 measures a small differential voltage on a high-side shunt resistor and translates it into a ground-referenced output voltage. The gain is internally fixed.

Wide input common-mode voltage range, low quiescent current, and tiny SOT23 packaging enable use in a wide variety of applications.

L
SOT23-5
(Plastic package)



Pin connections
(top view)



The input common-mode and power supply voltages are independent. The common-mode voltage can range from 2.8 to 30 V in operating conditions and up to 60 V in absolute maximum rating conditions.

The current consumption below 300 µA and the wide supply voltage range enable the power supply to be connected to either side of the current measurement shunt with minimal error.

1 Application schematics and pin description

The TSC101 high-side current sense amplifier features a 2.8 to 30 V input common-mode range that is independent of the supply voltage. The main advantage of this feature is that it allows high-side current sensing at voltages much greater than the supply voltage (V_{CC}).

Figure 1. Application schematics

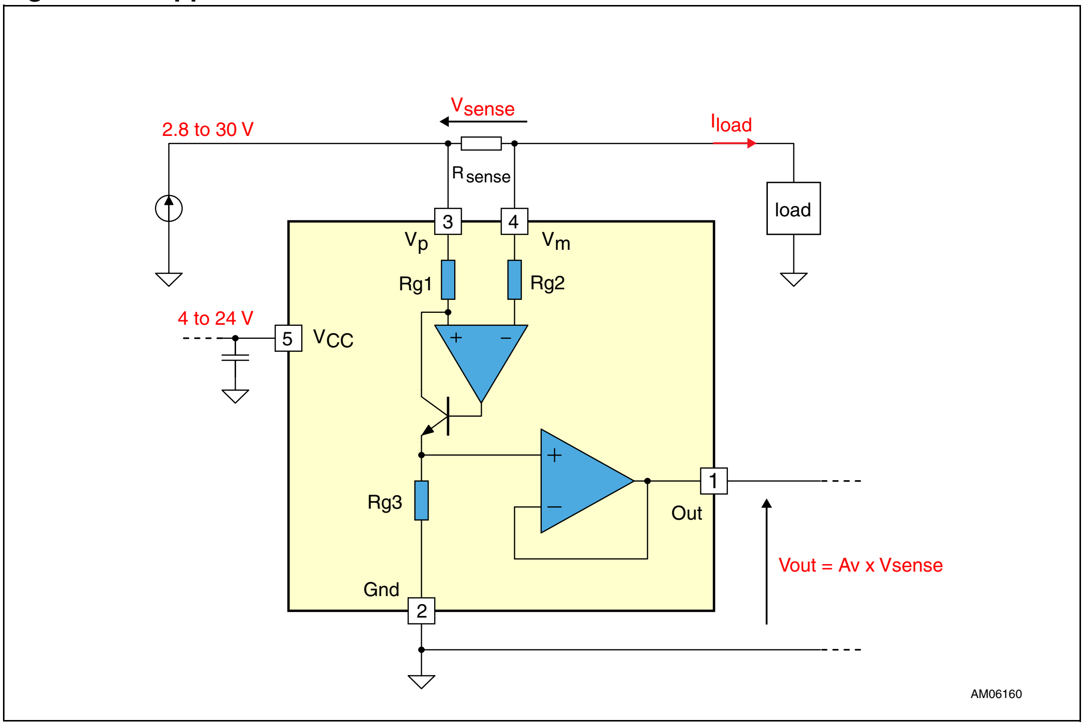


Table 1 describes the function of each pin. The pin positions are shown in the illustration on the cover page and in *Figure 1* above.

Table 1. Pin descriptions

Symbol	Type	Function
Out	Analog output	Output voltage, proportional to the magnitude of the sense voltage V_p-V_m.
Gnd	Power supply	Ground line
V_{CC}	Power supply	Positive power supply line
V_p	Analog input	Connection for the external sense resistor. The measured current enters the shunt on the V_p side.
V_m	Analog input	Connection for the external sense resistor. The measured current exits the shunt on the V_m side.

2 Absolute maximum ratings and operating conditions

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{id}	Input pins differential voltage (V_p-V_m)	±60	V
V_i	Input pin voltages (V_p and V_m)(1)	-0.3 to 60	V
V_{CC}	DC supply voltage(1)	-0.3 to 25	V
V_{out}	DC output pin voltage(1)	-0.3 to V_{CC}	V
T_{stg}	Storage temperature	-55 to 150	°C
T_j	Maximum junction temperature	150	°C
R_{thja}	SOT23-5 thermal resistance junction to ambient	250	°C/W
ESD	HBM: human body model(2)	2.5	kV
	MM: machine model(3)	150	V
	CDM: charged device model(4)	1.5	kV

1. Voltage values are measured with respect to the ground pin.
2. Human body model: a 100 pF capacitor is charged to the specified voltage, then discharged through a 1.5kΩ resistor between two pins of the device. This is done for all couples of connected pin combinations while the other pins are floating.
3. Machine model: a 200 pF capacitor is charged to the specified voltage, then discharged directly between two pins of the device with no external series resistor (internal resistor < 5 Ω). This is done for all couples of connected pin combinations while the other pins are floating.
4. Charged device model: all pins plus package are charged together to the specified voltage and then discharged directly to the ground.

Table 3. Operating conditions

Symbol	Parameter	Value	Unit
V_{CC}	DC supply voltage from T_{min} to T_{max}	4.0 to 24	V
T_{oper}	Operational temperature range (T_{min} to T_{max})	-40 to 125	°C
V_{icm}	Common mode voltage range	2.8 to 30	V

3 Electrical characteristics

Table 4. Supply[(1)]

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I_{CC}	Total supply current	V_{sense} = 0 V $T_{min} < T_{amb} < T_{max}$		165	300	µA

1. Unless otherwise specified, the test conditions are T_{amb} = 25°C, V_{CC} = 12 V, $V_{sense} = V_p$-V_m = 50 mV, V_m = 12 V, no load on Out.

Table 5. Input[(1)]

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
CMR	Common mode rejection Variation of V_{out} versus V_{icm} referred to input[(2)]	2.8 V < V_{icm} < 30 V $T_{min} < T_{amb} < T_{max}$	90	105		dB
SVR	Supply voltage rejection Variation of V_{out} versus V_{CC}[(3)]	4.0 V < V_{CC} < 24 V V_{sense} = 30 mV $T_{min} < T_{amb} < T_{max}$	90	105		dB
V_{os}	Input offset voltage[(4)]	T_{amb} = 25° C $T_{min} < T_{amb} < T_{max}$		±0.2 ±0.9	±1.5 ±2.3	mV
dV_{os}/dT	Input offset drift vs. T	$T_{min} < T_{amb} < T_{max}$		-3		µV/°C
I_{lk}	Input leakage current	V_{CC} = 0 V $T_{min} < T_{amb} < T_{max}$			1	µA
I_{ib}	Input bias current	V_{sense} = 0 V $T_{min} < T_{amb} < T_{max}$		5.5	8	µA

1. Unless otherwise specified, the test conditions are T_{amb} = 25°C, V_{CC} = 12 V, $V_{sense} = V_p$-V_m = 50 mV, V_m = 12 V, no load on Out.
2. See *Section 4.1: Common mode rejection ratio (CMR) on page 11* for the definition of CMR.
3. See *Section 4.2: Supply voltage rejection ratio (SVR) on page 11* for the definition of SVR.
4. See *Section 4.3: Gain (Av) and input offset voltage (V_{os}) on page 11* for the definition of V_{os}.

Table 6. Output(1)

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
Av	Gain	TSC101A TSC101B TSC101C		20 50 100		V/V
ΔAv	Gain accuracy	$T_{amb} = 25°C$ $T_{min} < T_{amb} < T_{max}$			±2.5 ±4.5	%
$\Delta V_{out}/\Delta T$	Output voltage drift vs. T(2)	$T_{min} < T_{amb} < T_{max}$		0.4		mV/°C
$\Delta V_{out}/\Delta I_{out}$	Output stage load regulation	-10 mA < I_{out} <10 mA I_{out} sink or source current		3	4	mV/mA
ΔV_{out}	Total output voltage accuracy(3)	V_{sense} = 50 mV T_{amb} = 25° C $T_{min} < T_{amb} < T_{max}$			±2.5 ±4.5	%
ΔV_{out}	Total output voltage accuracy	V_{sense} = 100 mV T_{amb} = 25° C $T_{min} < T_{amb} < T_{max}$			±3.5 ±5	%
ΔV_{out}	Total output voltage accuracy	V_{sense} = 20 mV T_{amb} = 25° C $T_{min} < T_{amb} < T_{max}$			±8 ±11	%
ΔV_{out}	Total output voltage accuracy	V_{sense} = 10 mV T_{amb} = 25° C $T_{min} < T_{amb} < T_{max}$			±15 ±20	%
$I_{sc\text{-}sink}$	Short-circuit sink current	Out connected to V_{CC}, V_{sense} = -1 V	30	60		mA
$I_{sc\text{-}source}$	Short-circuit source current	Out connected to Gnd V_{sense} = 1 V	15	26		mA
V_{oh}	Output stage high-state saturation voltage $V_{oh}=V_{CC}-V_{out}$	V_{sense} = 1 V I_{out} = 1 mA		0.8	1	V
V_{ol}	Output stage low-state saturation voltage	V_{sense} = -1 V I_{out} = 1 mA		50	100	mV

1. Unless otherwise specified, the test conditions are T_{amb} = 25°C, V_{CC} = 12 V, $V_{sense} = V_p - V_m$ = 50 mV, V_m = 12 V, no load on Out.
2. See *Output voltage drift versus temperature on page 12* for the definition.
3. Output voltage accuracy is the difference with the expected theoretical output voltage $V_{out\text{-}th} = Av{*}V_{sense}$. See *Output voltage accuracy on page 13* for a more detailed definition.

Table 7. Frequency response(1)

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
ts	Output settling to 1% final value	V_{sense} = 10 mV to 100 mV C_{load} = 47 pF(2) TSC101A TSC101B TSC101C		3 6 10		µs
SR	Slew rate	V_{sense} = 10 mV to 100 mV	0.55	0.9		V/µs
BW	3dB bandwidth	C_{load} = 47 pF(2) V_{sense} = 100 mV TSC101A TSC101B TSC101C		500 670 450		kHz

1. Unless otherwise specified, the test conditions are T_{amb} = 25°C, V_{CC} = 12 V, V_{sense} = V_p-V_m = 50 mV, V_m = 12 V, no load on Out.
2. For stability purposes, we do not recommend using a greater value of load capacitor.

Table 8. Noise(1)

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
	Total output voltage noise			50		$nV/\sqrt{Hz}$

1. Unless otherwise specified, the test conditions are T_{amb} = 25°C, V_{CC} = 12 V, V_{sense} = V_p-V_m = 50 mV, V_m = 12 V, no load on Out.

3.1 Electrical characteristics curves

For the following curves, the tested device is a TSC101C, and the test conditions are T_{amb}= 25°C, V_{CC} = 12 V, V_{sense} = V_p-V_m = 50 mV, V_m = 12 V, no load on Out unless otherwise specified.

Figure 2. Supply current vs. supply voltage (V_{sense} = 0 V)

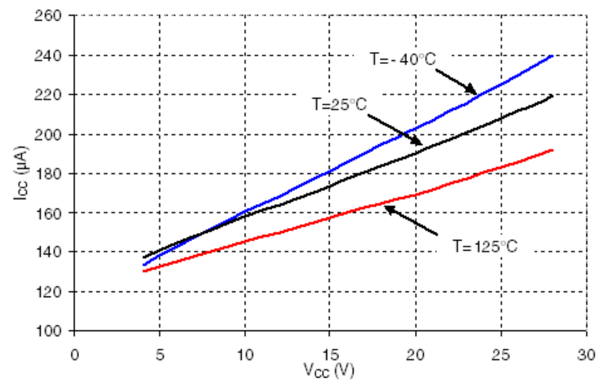


Figure 3. Supply current vs. V_{sense}

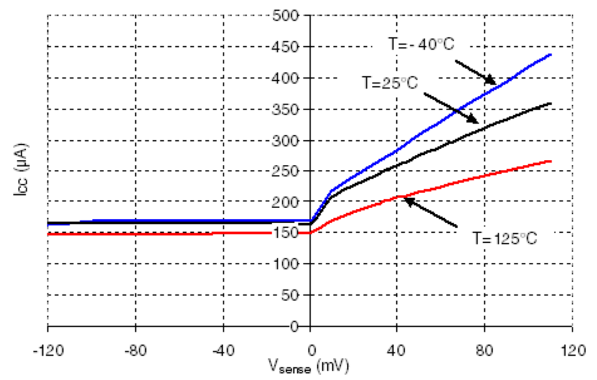


Figure 4. V_p pin input bias current vs. V_{sense}

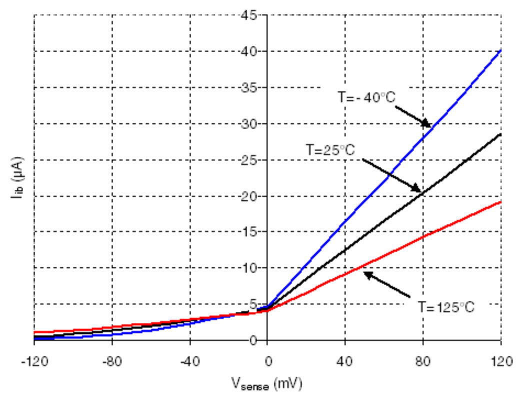


Figure 5. V_m pin input bias current vs. V_{sense}

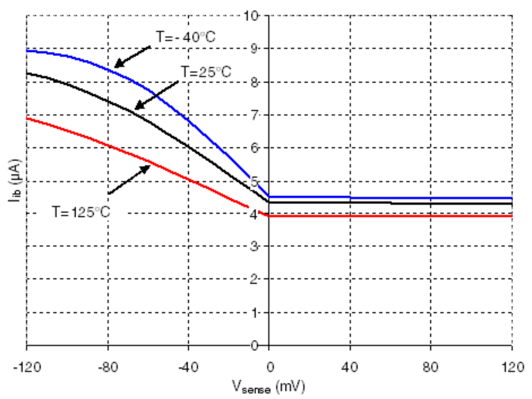


Figure 6. Minimum common mode operating voltage vs. temperature

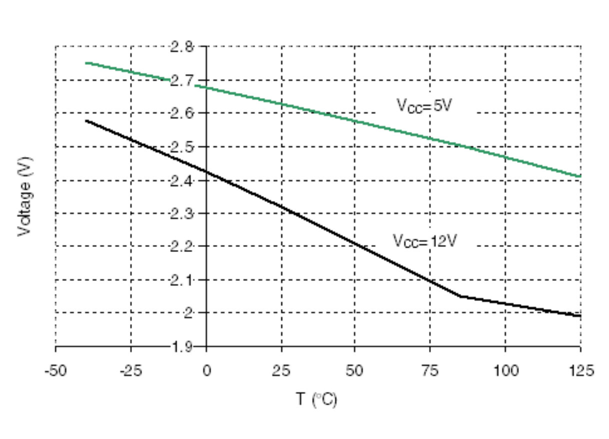


Figure 7. Output stage low-state saturation voltage versus output current (V_{sense} = -1 V)

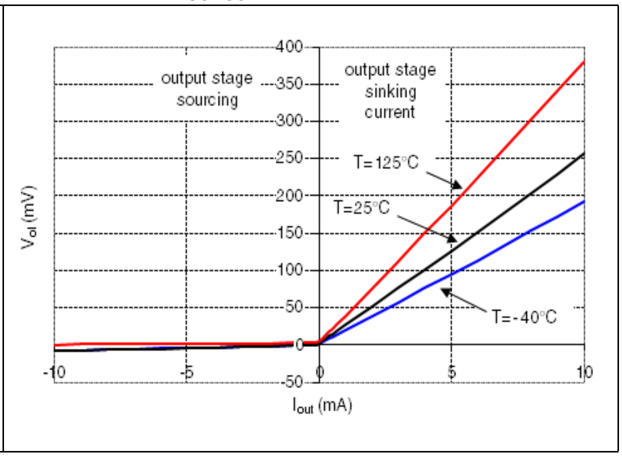


Figure 8. Output stage high-state saturation voltage versus output current (V_{sense} = +1 V)

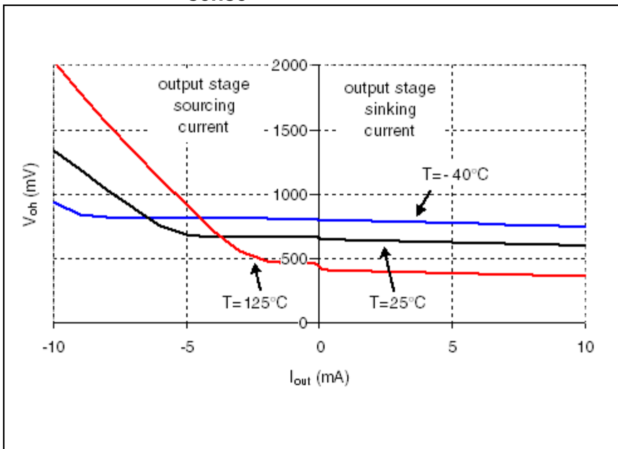


Figure 9. Output short-circuit source current versus temperature (Out pin connected to ground)

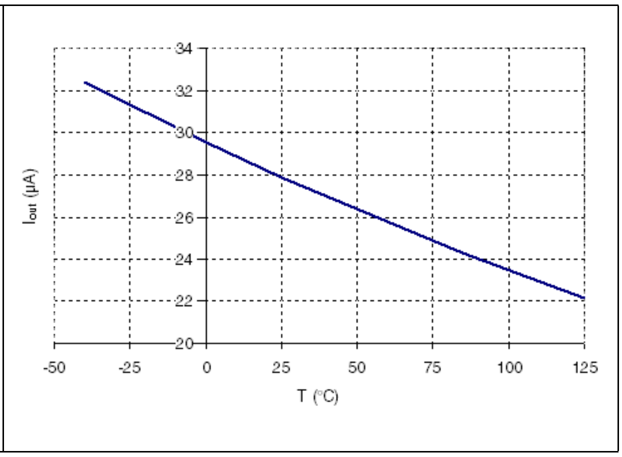


Figure 10. Output short-circuit sink current versus temperature (Out pin connected to V_{CC})

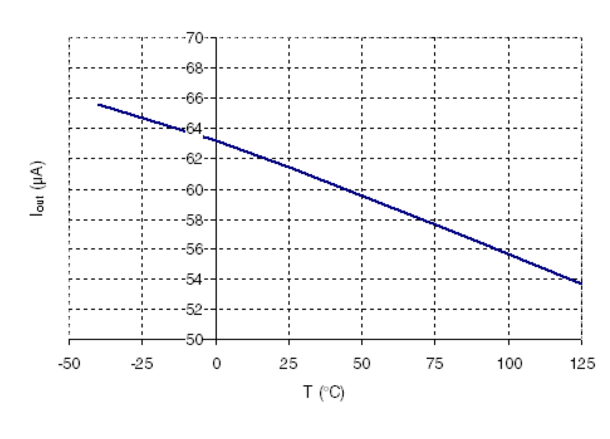


Figure 11. Output stage load regulation

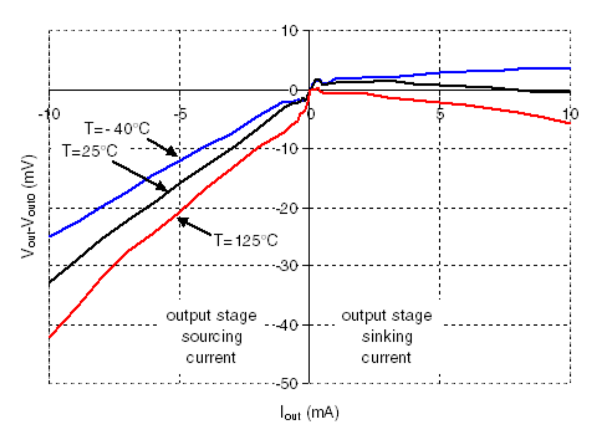


Figure 12. Input offset drift versus temperature

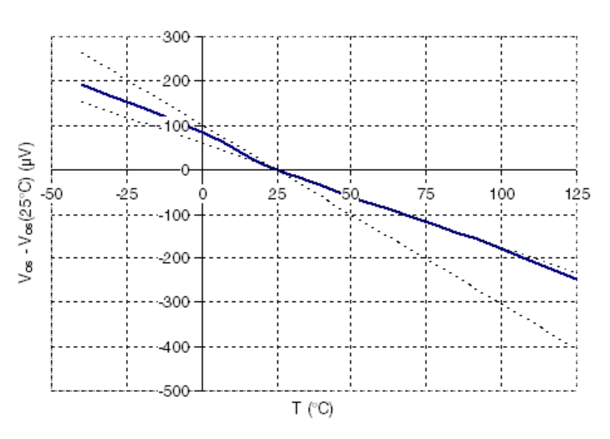


Figure 13. Output voltage drift versus temperature

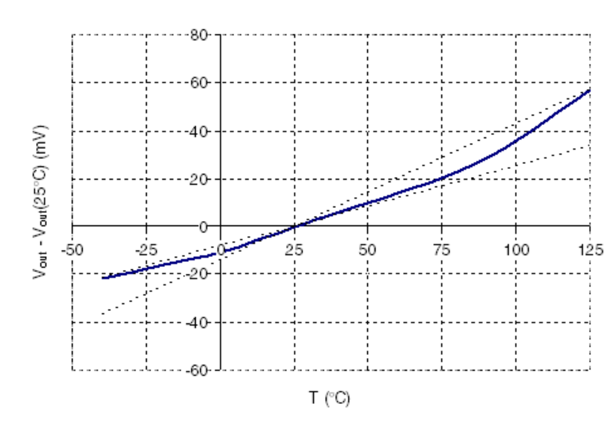


Figure 14. Bode diagram (V_{sense}=100mV)

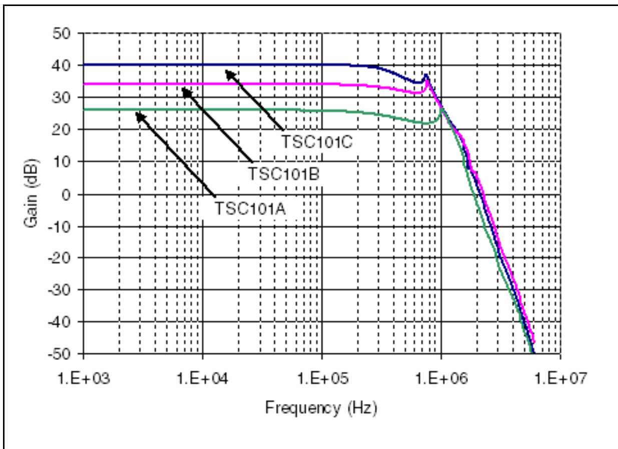


Figure 15. Power-supply rejection ratio versus frequency

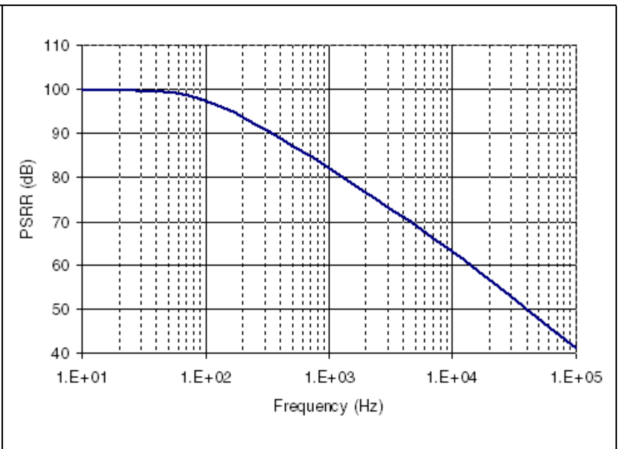


Figure 16. Total output voltage accuracy versus V_{sense}

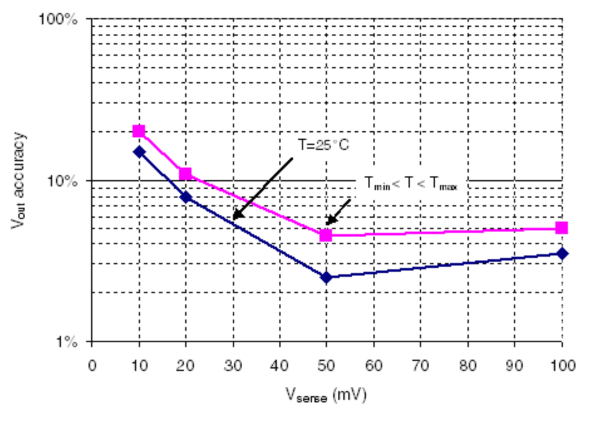


Figure 17. Output voltage versus V_{sense}

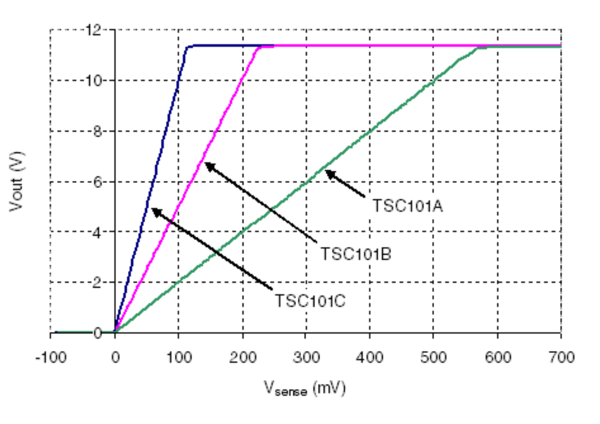


Figure 18. Output voltage versus V_{sense} (detail for low V_{sense} values)

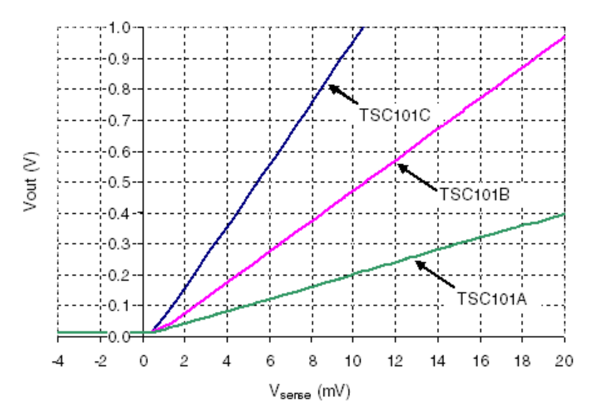
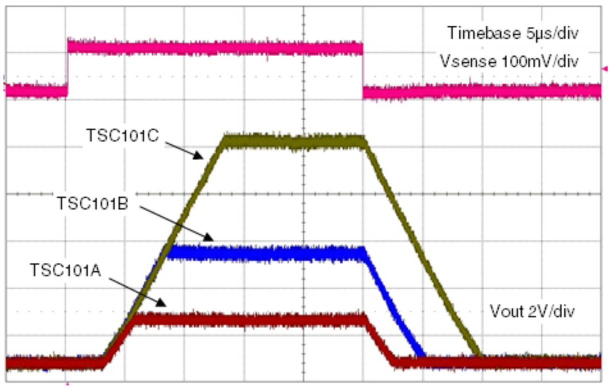


Figure 19. Step response



4 Parameter definitions

4.1 Common mode rejection ratio (CMR)

The common-mode rejection ratio (CMR) measures the ability of the current-sensing amplifier to reject any DC voltage applied on both inputs V_p and V_m. The CMR is referred back to the input so that its effect can be compared with the applied differential signal. The CMR is defined by the formula:

$$CMR = -20 \cdot \log \frac{\Delta V_{out}}{\Delta V_{icm} \cdot Av}$$

4.2 Supply voltage rejection ratio (SVR)

The supply-voltage rejection ratio (SVR) measures the ability of the current-sensing amplifier to reject any variation of the supply voltage V_{CC}. The SVR is referred back to the input so that its effect can be compared with the applied differential signal. The SVR is defined by the formula:

$$SVR = -20 \cdot \log \frac{\Delta V_{out}}{\Delta V_{CC} \cdot Av}$$

4.3 Gain (Av) and input offset voltage (V_{os})

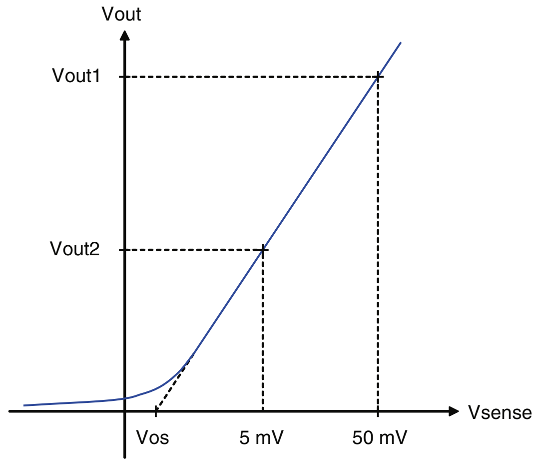
The input offset voltage is defined as the intersection between the linear regression of the V_{out} versus V_{sense} curve with the X-axis (see *Figure 20*). If V_{out1} is the output voltage with $V_{sense}=V_{sense1}=50mV$ and V_{out2} is the output voltage with $V_{sense}=V_{sense2}=5mV$, then V_{os} can be calculated with the following formula:

$$V_{os} = V_{sense1} - \left(\frac{V_{sense1} - V_{sense2}}{V_{out1} - V_{out2}} \cdot V_{out1} \right)$$

The amplification gain A_v is defined as the ratio between output voltage and input differential voltage:

$$Av = \frac{V_{out}}{V_{sense}}$$

Figure 20. V_{out} versus V_{sense} characteristics: detail for low V_{sense} values



4.4 Output voltage drift versus temperature

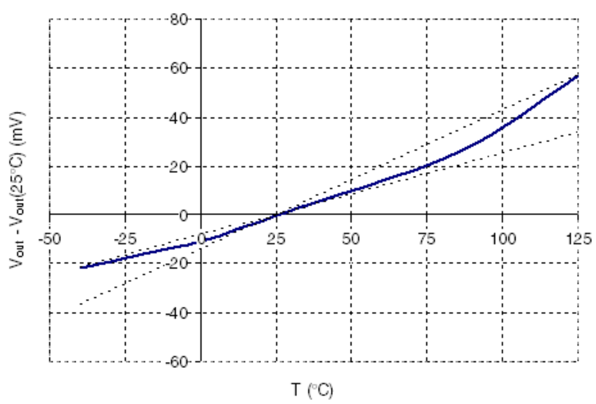
The output voltage drift versus temperature is defined as the maximum variation of V_{out} with respect to its value at 25°C, over the temperature range. It is calculated as follows:

$$\frac{\Delta V_{out}}{\Delta T} = \max \frac{V_{out}(T_{amb}) - V_{out}(25°C)}{T_{amb} - 25°C}$$

with $T_{min} < T_{amb} < T_{max}$.

Figure 21 provides a graphical definition of output voltage drift versus temperature. On this chart, V_{out} is always comprised in the area defined by dotted lines representing the maximum and minimum variation of V_{out} versus T.

Figure 21. Output voltage drift versus temperature



4.5 Output voltage accuracy

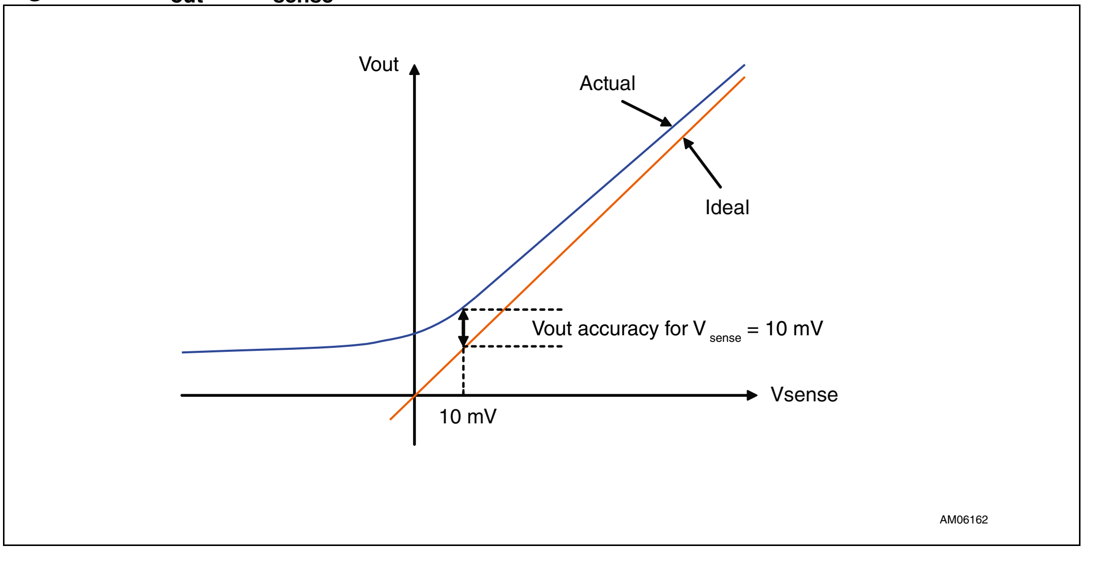
The output voltage accuracy is the difference between the actual output voltage and the theoretical output voltage. Ideally, the current sensing output voltage should be equal to the input differential voltage multiplied by the theoretical gain, as in the following formula:

$$V_{out\text{-}th} = A_v \cdot V_{sense}$$

The actual value is very slightly different, mainly due to the effects of:

- the input offset voltage V_{os},
- non-linearity

Figure 22. V_{out} vs. V_{sense} theoretical and actual characteristics



The output voltage accuracy, expressed in percentage, can be calculated with the following formula:

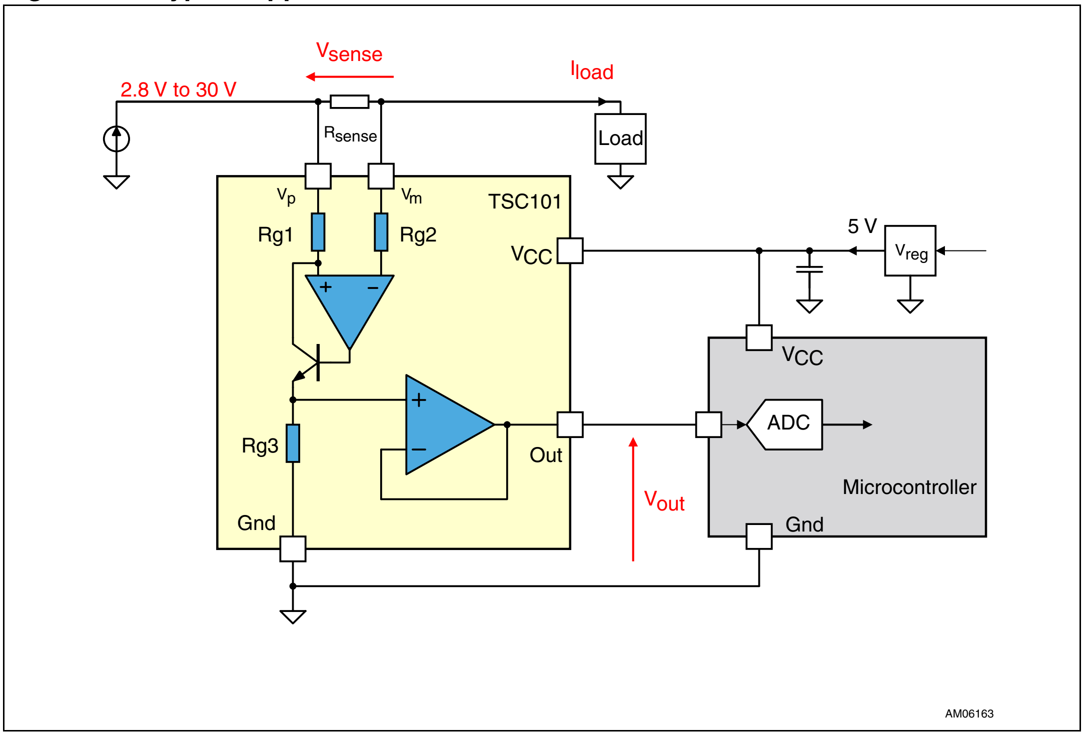
$$\Delta V_{out} = \frac{abs(V_{out} - (A_v \cdot V_{sense}))}{A_v \cdot V_{sense}}$$

with A_v = 20 V/V for TSC101A, A_v = 50 V/V for TSC101B and A_v = 100 V/V for TSC101C.

5 Application information

The TSC101 can be used to measure current and to feed back the information to a microcontroller, as shown in *Figure 23*.

Figure 23. Typical application schematic



The current from the supply flows to the load through the R_{sense} resistor causing a voltage drop equal to V_{sense} across R_{sense}. The amplifier input currents are negligible, therefore its inverting input voltage is equal to V_m. The amplifier's open-loop gain forces its non-inverting input to the same voltage as the inverting input. As a consequence, the amplifier adjusts current flowing through Rg1 so that the voltage drop across Rg1 exactly matches V_{sense}.

Therefore, the drop across Rg1 is: $V_{Rg1}=V_{sense}=R_{sense}.I_{load}$

If I_{Rg1} is the current flowing through Rg1, then I_{Rg1} is given by the formula: $I_{Rg1}=V_{sense}/Rg1$

The I_{Rg1} current flows entirely into resistor R_{g3} (the input bias current of the buffer is negligible). Therefore, the voltage drop on the R_{g3} resistor can be calculated as follows:

$$V_{Rg3}=R_{g3}.I_{Rg1}=(R_{g3}/R_{g1}).V_{sense}$$

Because the voltage across the R_{g3} resistor is buffered to the Out pin, V_{out} can be expressed as:

$$V_{out}=(R_{g3}/R_{g1}).V_{sense} \text{ or } V_{out}=(R_{g3}/R_{g1}).R_{sense}.I_{load}$$

The resistor ratio R_{g3}/R_{g1} is internally set to 20V/V for TSC101A, to 50V/V for TSC101B and to 100V/V for TSC101C.
The R_{sense} resistor and the R_{g3}/R_{g1} resistor ratio (equal to A_v) are important parameters because they define the full scale output range of your application. Therefore, they must be selected carefully.

6 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK® is an ST trademark.

Figure 24. SOT23-5L package mechanical drawing

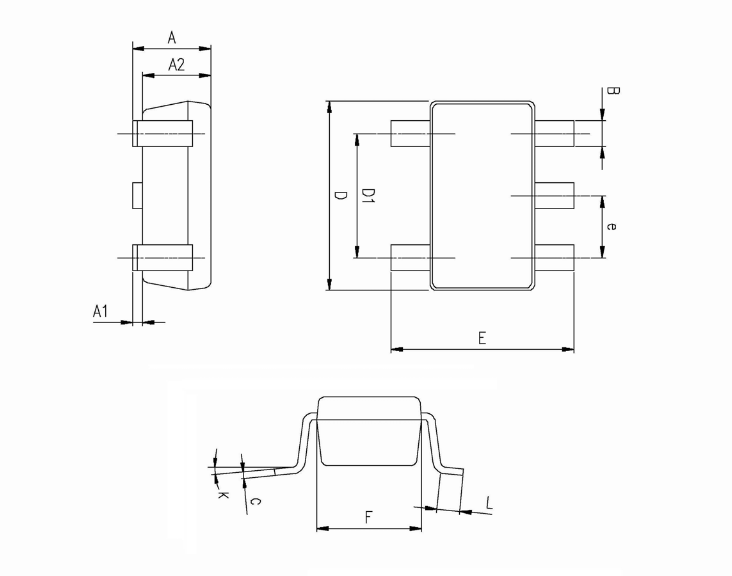


Table 9. SOT23-5L package mechanical data

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	0.90	1.20	1.45	0.035	0.047	0.057
A1			0.15			0.006
A2	0.90	1.05	1.30	0.035	0.041	0.051
B	0.35	0.40	0.50	0.013	0.015	0.019
C	0.09	0.15	0.20	0.003	0.006	0.008
D	2.80	2.90	3.00	0.110	0.114	0.118
D1		1.90			0.075	
e		0.95			0.037	
E	2.60	2.80	3.00	0.102	0.110	0.118
F	1.50	1.60	1.75	0.059	0.063	0.069
L	0.10	0.35	0.60	0.004	0.013	0.023
K	0 degrees		10 degrees			

7 Ordering information

Table 10. Order codes

Part number	Temperature range	Package	Packaging	Marking	Gain
TSC101AILT	-40°C, +125°C	SOT23-5	Tape & reel	O104	20
TSC101BILT				O105	50
TSC101CILT				O106	100
TSC101AIYLT(1)	-40°C, +125°C	SOT23-5 (Automotive grade)	Tape & reel	O101	20
TSC101BIYLT(1)				O102	50
TSC101CIYLT(1)				O103	100

1. Qualified and characterized according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 & Q 002 or equivalent.

8 Revision history

Table 11. Document revision history

Date	Revision	Changes
05-Mar-2007	1	First release, preliminary data.
22-Oct-2007	2	Document status promoted from preliminary data to datasheet. Added test results in electrical characteristics tables. Added electrical characteristics curves.
14-Mar-2011	3	Added ESD charged device model values in *Table 2: Absolute maximum ratings*. Added automotive grade qualification in *Table 10: Order codes*.